

100 V, 2 A PNP high power bipolar transistor

10 January 2014

Product data sheet

1. General description

PNP high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

NPN complement: PHPT61002NYC.

2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
 - High energy efficiency due to less heat generation

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-100	V
I _C	collector current		-	-	-2	А
I _{CM}	peak collector current	$t_p \le 1 \text{ ms}; \text{ pulsed}$	-	-	-6	А
R _{CEsat}	collector-emitter saturation resistance	$\begin{split} &I_{C} = -2 \text{ A}; I_{B} = -200 \text{ mA}; \text{ pulsed}; \\ &t_{p} \leq 300 \mu\text{s}; \delta \leq 0.02 ; T_{amb} = 25 ^{\circ}\text{C} \end{split}$	-	125	200	mΩ



100 V, 2 A PNP high power bipolar transistor

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	С
2	Е	emitter		в
3	Е	emitter	q	1×
4	В	base	មុច្ចមុ	sym132
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PHPT61002PYC	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT61002PYC	1002PCA

100 V, 2 A PNP high power bipolar transistor

8. Limiting values

Table 5.Limiting values

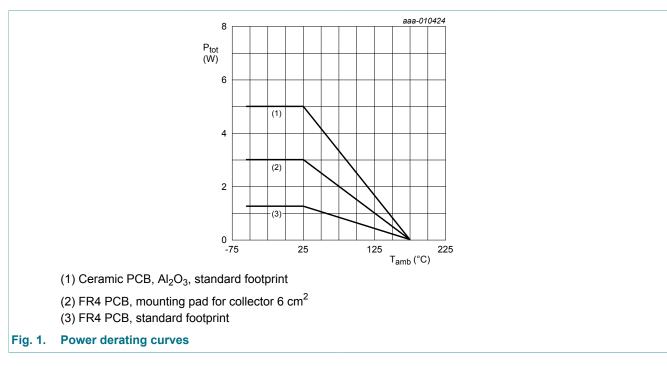
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-100	V
V _{CEO}	collector-emitter voltage	open base		-	-100	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-2	А
I _{CM}	peak collector current	$t_p \le 1 ms$; pulsed		-	-6	А
I _B	base current			-	-0.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.25	W
			[2]	-	3	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm².

- [3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [4] Power dissipation from junction to mounting base.



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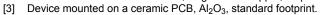
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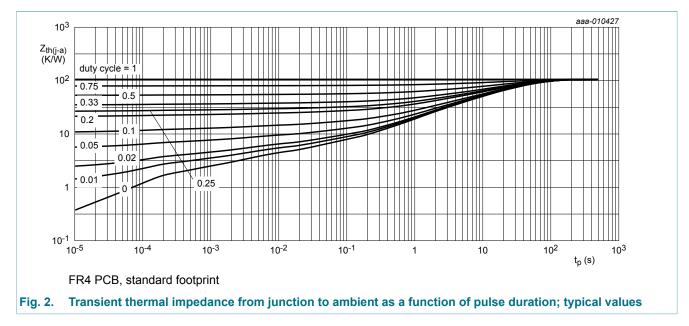
9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to		in free air	[1]	-	-	115	K/W
	from junction to ambient		[2]	-	-	50	K/W
ambient			[3]	-	-	30	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm².

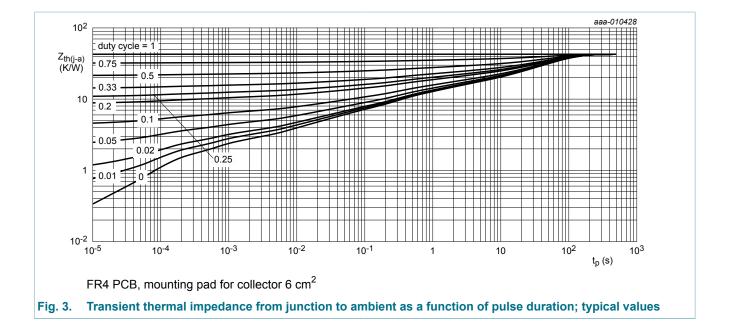




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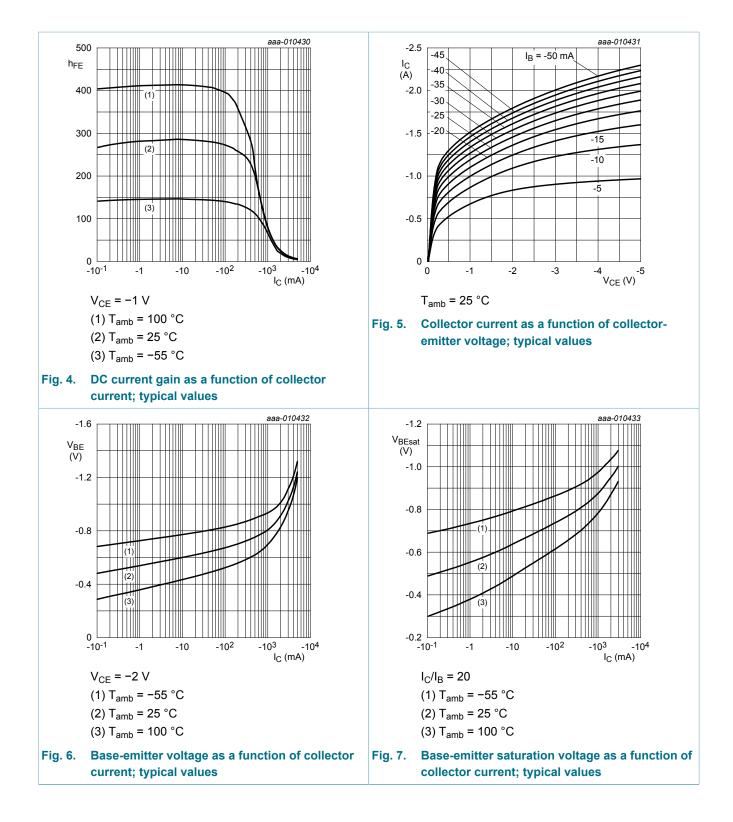
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V_{CB} = -80 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -80 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -80 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = -8 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -1.5 V; I _C = -500 mA; T _{amb} = 25 °C	100	150	-	
		V_{CE} = -10 V; I _C = -500 mA; T _{amb} = 25 °C	150	220	-	
		$V_{CE} = -10 \text{ V}; \text{ I}_{C} = -1 \text{ A}; \text{t}_{p} \leq 300 \mu\text{s};$ $\delta \leq 0.02 \text{ ; } \text{T}_{amb} = 25 ^{\circ}\text{C}\text{; } \text{pulsed}$	80	210	-	
		V_{CE} = -10 V; I _C = -2 A; pulsed; t _p ≤ 300 µs; δ ≤ 0.02 ; T _{amb} = 25 °C	20	100	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -500 mA; I_B = -50 mA; t_p ≤ 300 μs; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-70	-110	mV
		$\begin{split} I_{C} &= -2 \text{ A}; I_{B} = -200 \text{ mA}; t_{p} \leq 300 \mu\text{s}; \\ \delta &\leq 0.02 ; T_{amb} = 25 ^{\circ}\text{C}; \text{ pulsed} \end{split}$	-	-250	-400	mV
R _{CEsat}	collector-emitter saturation resistance	$\begin{split} &I_{C} = -2 \text{ A}; \ I_{B} = -200 \text{ mA}; \text{ pulsed}; \\ &t_{p} \leq 300 \mu\text{s}; \ \delta \leq 0.02 ; \ T_{amb} = 25 ^{\circ}\text{C} \end{split}$	-	125	200	mΩ
V _{BEsat}	base-emitter saturation voltage	I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-1.02	-1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I _C = -0.1 A; T _{amb} = 25 °C	-	-0.67	-0.9	V
t _d	delay time	V_{CC} = -12.5 V; I_{C} = -1 A; I_{Bon} = -50 mA;	-	20	-	ns
r	rise time	I _{Boff} = 50 mA; T _{amb} = 25 °C	-	180	-	ns
on	turn-on time		-	200	-	ns
S	storage time		-	350	-	ns
f	fall time		-	220	-	ns
off	turn-off time	-	-	570	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C	-	125	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	28	-	pF

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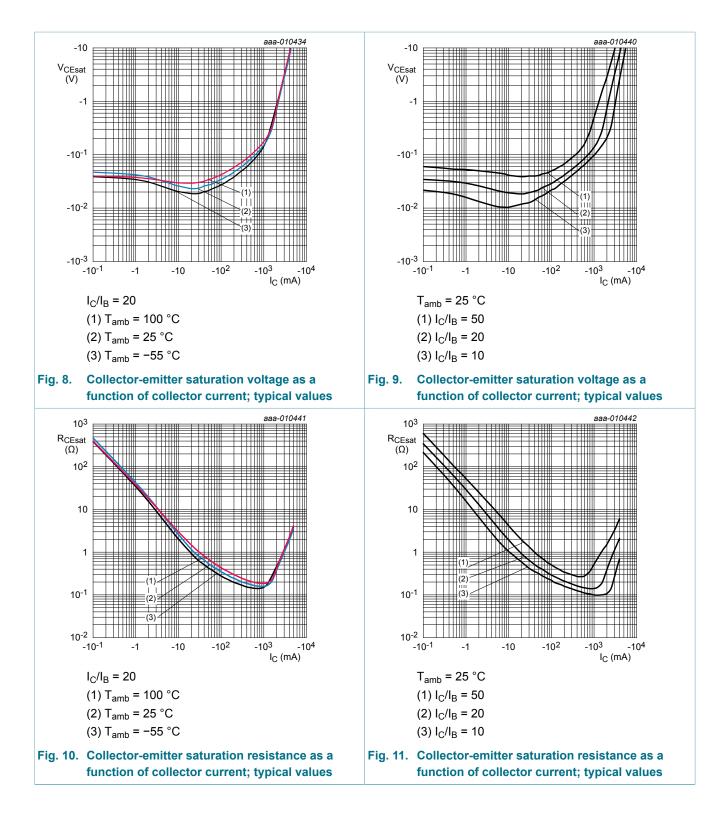
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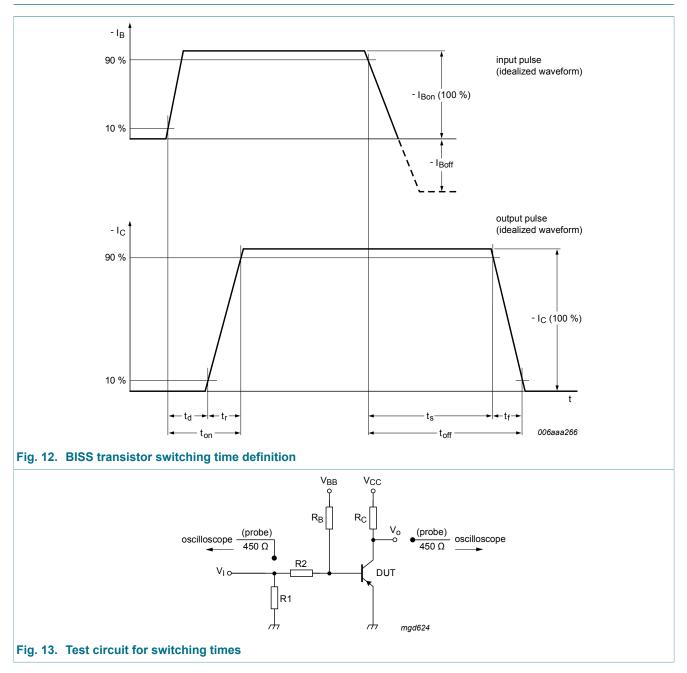


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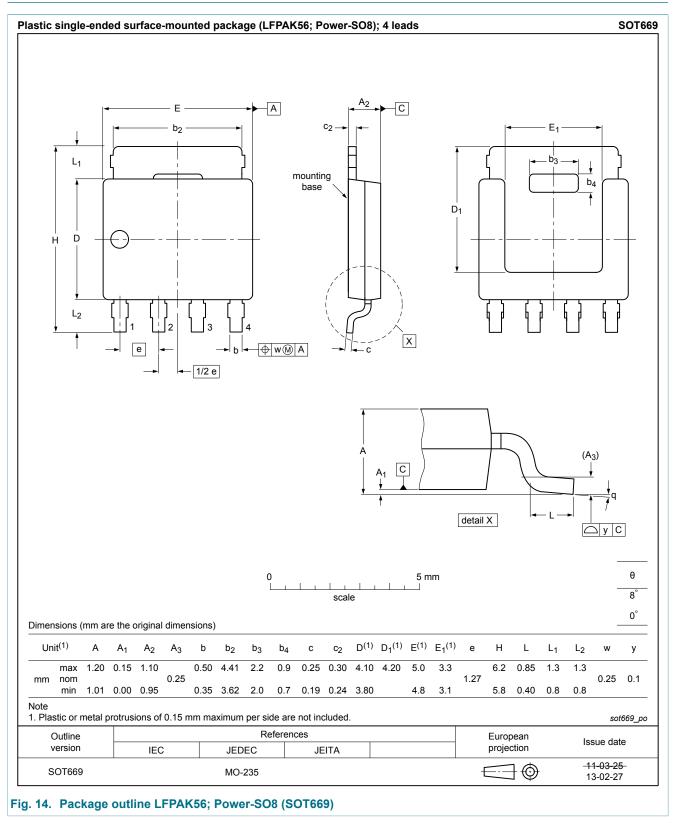
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11. Test information

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12. Package outline



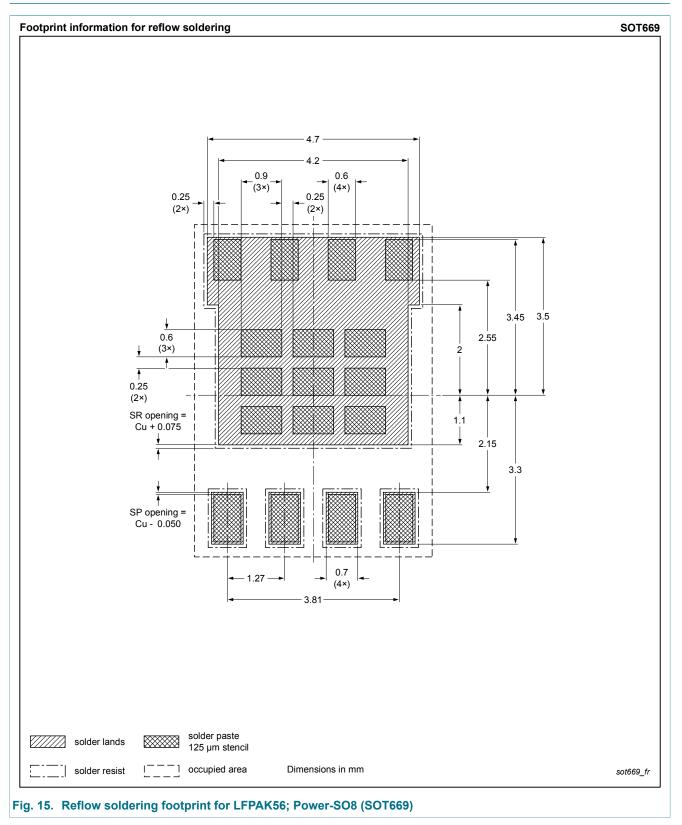
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100 V, 2 A PNP high power bipolar transistor

13. Soldering



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14. Revision history

Table 8. Revision his	Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PHPT61002PYC v.1	20140110	Product data sheet	-	-			

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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100 V, 2 A PNP high power bipolar transistor

16. Contents

1	General description1
2	Features and benefits1
3	Applications1
4	Quick reference data 1
5	Pinning information2
6	Ordering information2
7	Marking2
8	Limiting values3
9	Thermal characteristics4
10	Characteristics6
11	Test information9
12	Package outline 10
13	Soldering11
14	Revision history12
15	Legal information13
15.1	Data sheet status 13
15.2	Definitions13
15.3	Disclaimers13
15.4	Trademarks 14

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